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**TPD6S300** 

SLVSDK3C-SEPTEMBER 2016-REVISED JANUARY 2017

# TPD6S300 USB Type-C<sup>™</sup> Port Protector: Short-to-V<sub>BUS</sub> Overvoltage and IEC ESD Protection

#### Features 1

- 4-Channels of Short-to-V<sub>BUS</sub> Overvoltage Protection (CC1, CC2, SBU1, SBU2): 24-V<sub>DC</sub> Tolerant
- 6-Channels of IEC 61000-4-2 ESD Protection (CC1, CC2, SBU1, SBU2, DP, DM)
- CC1, CC2 Overvoltage Protection FETs 600 mA • capable for passing V<sub>CONN</sub> power
- CC Dead Battery Resistors integrated for handling dead battery use case in mobile devices
- 3-mm × 3-mm WQFN Package

#### 2 Applications

- Laptop PC
- Tablets
- Smartphones
- Monitors and TVs
- **Docking Stations**

## 3 Description

The TPD6S300 is a single chip USB Type-C port protection solution that provides 20-V Short-to-V<sub>BUS</sub> overvoltage and IEC ESD protection.

Since the release of the USB Type-C connector, many products and accessories for USB Type-C have been released which do not meet the USB Type-C specification. One example of this is USB Type-C Power Delivery adaptors that only place 20 V on the V<sub>BUS</sub> line. Another concern for USB Type-C is that mechanical twisting and sliding of the connector could short pins due to the close proximity they have in this small connector. This can cause 20-V  $\rm V_{BUS}$  to be shorted to the CC and SBU pins. Also, due to the close proximity of the pins in the Type-C connector, there is a heightened concern that debris and moisture will cause the 20-V V<sub>BUS</sub> pin to be shorted to the CC and SBU pins.

These non-ideal equipments and mechanical events make it necessary for the CC and SBU pins to be 20-V tolerant, even though they only operate at 5 V or lower. The TPD6S300 enables the CC and SBU pins to be 20-V tolerant without interfering with normal operation by providing overvoltage protection on the CC and SBU pins. The device places high voltage FETs in series on the SBU and CC lines. When a voltage above the OVP threshold is detected on these lines, the high voltage switches are opened up, isolating the rest of the system from the high voltage condition present on the connector.

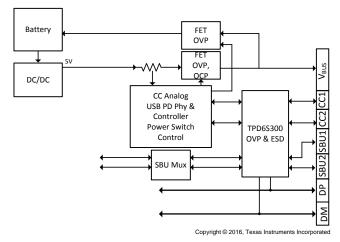
Finally, most systems require IEC 61000-4-2 system level ESD protection for their external pins. The TPD6S300 integrates IEC 61000-4-2 ESD protection for the CC1, CC2, SBU1, SBU2, DP, DM pins, removing the need to place high voltage TVS diodes externally on the connector.

## Device Information<sup>(1)</sup>

PART NUMBER	BER PACKAGE BODY SIZE (NO	
TPD6S300	WQFN (20)	3.00 mm × 3.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

## Application Diagram



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# 4 Revision History

Changes from Revision B (November 2016) to Revision C	Page
<ul> <li>Changed units from µs to ns for OVP_RESPONSE in the <i>Timing Requirements</i> table</li> </ul>	
Changes from Revision A (September 2016) to Revision B	Page
First public release of the data sheet	

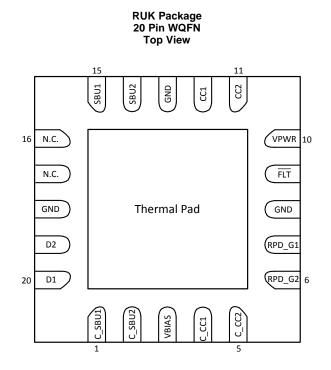
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## 5 Device Comparison Table

Part Number	Over Voltage Protected Channels	IEC 61000-4-2 ESD Protected Channels
TPD6S300	4-Ch (CC1, CC2, SBU1, SBU2)	6-Ch (CC1, CC2, SBU1, SBU2, DP, DM)
TPD8S300	4-Ch (CC1, CC2, SBU1, SBU2)	8-Ch (CC1, CC2, SBU1, SBU2, DP_T, DM_T, DP_B, DM_B)

## 6 Pin Configuration and Functions



#### **Pin Functions**

PIN NO. NAME		TYPE	DECODIDION		
		TYPE	DESCRIPTION		
1	C_SBU1	I/O	Connector side of the SBU1 OVP FET. Connect to either SBU pin of the USB Type-C connector		
2	C_SBU2	I/O	Connector side of the SBU2 OVP FET. Connect to either SBU pin of the USB Type-C connector		
3	VBIAS	Power	Pin for ESD support capacitor. Place a 0.1-µF capacitor on this pin to ground		
4	C_CC1	I/O	connector side of the CC1 OVP FET. Connect to either CC pin of the USB Type-C connector		
5	C_CC2	I/O	Connector side of the CC2 OVP FET. Connect to either CC pin of the USB Type-C connector		
6	RPD_G2	I/O	Short to C_CC2 if dead battery resistors are needed. If dead battery resistors are not needed, short pin to GND		
7	RPD_G1	I/O	Short to C_CC1 if dead battery resistors are needed. If dead battery resistors are not needed, short pin to GND		
8	GND	GND	Ground		
9	FLT	0	Open drain for fault reporting		
10	V <sub>PWR</sub>	Power	2.7-V-3.6-V power supply		

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## Pin Functions (continued)

PIN NO. NAME		TYDE	DESCRIPTION		
		TYPE	DESCRIPTION		
11	CC2	I/O	System side of the CC2 OVP FET. Connect to either CC pin of the CC/PD controller		
12	CC1	I/O	System side of the CC1 OVP FET. Connect to either CC pin of the CC/PD controller		
13	GND	GND	round		
14	SBU2	I/O	vstem side of the SBU2 OVP FET. Connect to either SBU pin of the SBU MUX		
15	SBU1	I/O	System side of the SBU1 OVP FET. Connect to either SBU pin of the SBU MUX		
16	N.C.	I/O	Unused pin. Connect to Ground		
17	N.C.	I/O	Unused pin. Connect to Ground		
18	GND	GND	Ground		
19	D2	I/O	USB2.0 IEC ESD protection. Connect to any of the USB2.0 pins of the USB Type-C connector		
20	D1	I/O	USB2.0 IEC ESD protection. Connect to any of the USB2.0 pins of the USB Type-C connector		
_	Thermal Pad	GND	Internally connected to GND. Used as a heatsink. Connect to the PCB GND plane		



## 7 Specifications

## 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V		V <sub>PWR</sub>	-0.3	5	V
VI	Input voltage	RPD_G1, RPD_G2	-0.3	24	V
V <sub>O</sub> Output voltage	FLT	-0.3	6	V	
	Output voltage	VBIAS	-0.3	24	V
		D1, D2	-0.3	6	V
V <sub>IO</sub>	I/O voltage	CC1, CC2, SBU1, SBU2	-0.3	6	V
		C_CC1, C_CC2, C_SBU1, C_SBU2	-0.3	24	V
T <sub>A</sub>	Operating free air temperature		-40	85	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 7.2 ESD Ratings—JEDEC Specification

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 $^{(2)}$	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±2000 V may actually have higher performance.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Pins listed as ±500 V may actually have higher performance.

## 7.3 ESD Ratings—IEC Specification

			VALUE	UNIT		
V <sub>(ESD)</sub>	Electrostatic discharge <sup>(1)</sup>	IEC 61000-4-2, C_CC1, C_CC2, D1, D2	Contact discharge	±8000		
			Air-gap discharge	±15000	V	
		IEC 61000-4-2, C_SBU1, C_SBU2	Contact discharge	±6000	v	
			Air-gap discharge	±15000		

(1) Tested on the TPD6S300 EVM connected to the TPS65982 EVM.

## 7.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V		V <sub>PWR</sub>	2.7	3.3	4.5	V
VI	Input voltage	RPD_G1, RPD_G2	0		5.5	V
Vo	Output voltage	FLT pull-up resistor power rail	2.7		5.5	V
		D1, D2	-0.3		5.5	V
V <sub>IO</sub>	I/O voltage	CC1, CC2, C_CC1, C_CC2	0		5.5	V
		SBU1, SBU2, C_SBU1, C_SBU2	0		4.3	V
I <sub>VCONN</sub>	V <sub>CONN</sub> current	Current flowing into CC1/2 and flowing out of C_CC1/2, VCCx – VC_CCx ≤ 250 mV			600	mA
I <sub>VCONN</sub>	V <sub>CONN</sub> current	Current flowing into CC1/2 and flowing out of C_CC1/2, $T_J \le 105^{\circ}C$			1.25	А

## **Recommended Operating Conditions (continued)**

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
	FLT pull-up resistance	1.7		300	kΩ
External components <sup>(1)</sup>	VBIAS capacitance <sup>(2)</sup>		0.1		μF
	V <sub>PWR</sub> capacitance	0.3	1		μF

(1) For recommended values for capacitors and resistors, the typical values assume a component placed on the board near the pin. Minimum and maximum values listed are inclusive of manufacturing tolerances, voltage derating, board capacitance, and temperature variation. The effective value presented must be within the minimum and maximums listed in the table.

(2) The VBIAS pin requires a minimum 35-V<sub>DC</sub> rated capacitor. A 50-V<sub>DC</sub> rated capacitor is recommended to reduce capacitance derating. See the VBIAS Capacitor Selection section for more information on selecting the VBIAS capacitor.

## 7.5 Thermal Information

		TPD6S300	
	THERMAL METRIC <sup>(1)</sup>	RUK (WQFN)	UNIT
		20 PINS	
$R_{ heta JA}$	Junction-to-ambient thermal resistance	45.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	48.8	°C/W
$R_{ heta JB}$	Junction-to-board thermal resistance	17.1	°C/W
ΨJT	Junction-to-top characterization parameter	0.6	°C/W
Ψјв	Junction-to-board characterization parameter	17.1	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	3.7	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

## 7.6 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CC OVP SW	TCHES					
D	On resistance of CC OVP FETs, $T_J \le 85^{\circ}C$	CCx = 5.5 V		278	392	mΩ
R <sub>ON</sub>				278	415	mΩ
R <sub>ON(FLAT)</sub>	On resistance flatness	Sweep CCx voltage between 0 V and 1.2 V			5	mΩ
C <sub>ON_CC</sub>	Equivalent on capacitance	Capacitance from C_CCx or CCx to GND when device is powered. VC_CCx/VCCx = 0 V to 1.2 V, f = 400 kHz	60	74	120	pF
R <sub>D</sub>	Dead battery pull-down resistance (only present when device is unpowered). Effective resistance of $R_D$ and FET in series	V_C_CCx = 2.6 V	4.1	5.1	6.1	kΩ
VTH_DB	Threshold voltage of the pulldown FET in series with RD during dead battery	I_CC = 80 μA	0.5	0.9	1.2	V
V <sub>OVPCC</sub>	OVP threshold on CC pins	Place 5.5 V on C <u>CC</u> x. Step up C_CCx until the FLT pin is asserted	5.75	6	6.2	V
V <sub>OVPCC_HYS</sub>	Hysteresis on CC OVP	Place 6.5 V on C_CCx. Step down the voltage on C_CCx until the FLT pin is deasserted. Measure difference between rising and falling OVP threshold for C_CCx		50		mV
BW <sub>ON</sub>	On bandwidth single ended (-3 dB)	Measure the –3-dB bandwidth from C_CCx to CCx. Single ended measurement, $50-\Omega$ system. Vcm = 0.1 V to 1.2 V		100		MHz



## **Electrical Characteristics (continued)**

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>STBUS_CC</sub>	Short-to-VBUS tolerance on the CC pins	Hot-Plug C_CCx with a 1 meter USB Type C Cable, place a $30-\Omega$ load on CCx			24	V
Vstbus_cc_cl amp	Short-to-VBUS system-side clamping voltage on the CC pins (CCx)	Hot-Plug C_CCx with a 1 meter USB Type C Cable. Hot-Plug voltage C_CCx = 24 V. VPWR = 3.3 V. Place a $30$ - $\Omega$ load on CCx		8		V
SBU OVP SW	ITCHES					
R <sub>ON</sub>	On resistance of SBU OVP FETs	SBUx = 3.6 V. $-40^{\circ}C \le T_{J} \le +85^{\circ}C$		4	6.5	Ω
R <sub>ON(FLAT)</sub>	On resistance flatness	Sweep SBUx voltage between 0 V and 3.6 V. –40°C $\leq$ T_J $\leq$ +85°C		0.7	1.5	Ω
C <sub>ON_SBU</sub>	Equivalent on capacitance	Capacitance from SBUx or C_SBUx to GND when device is powered. Measure at VC_SBUx/VSBUx = 0.3 V to 3.6 V		6		pF
V <sub>OVPSBU</sub>	OVP threshold on SBU pins	Place 3.6 V on C_ <u>SBU</u> x. Step up C_SBUx until the FLT pin is asserted	4.35	4.5	4.7	V
V <sub>OVPSBU_HYS</sub>	Hysteresis on SBU OVP	Place 5 V on C_CCx. Step down the voltage on C_CCx until the FLT pin is deasserted. Measure difference between rising and falling OVP threshold for C_SBUx		50		mV
BW <sub>ON</sub>	On bandwidth single ended (-3 dB)	Measure the $-3$ -dB bandwidth from C_SBUx to SBUx. Single ended measurement, 50- $\Omega$ system. Vcm = 0.1 V to 3.6 V		1000		MHz
X <sub>TALK</sub>	Crosstalk	Measure crosstalk at f = 1 MHz from SBU1 to C_SBU2 or SBU2 to C_SBU1. Vcm1 = 3.6 V, Vcm2 = 0.3 V. Be sure to terminate open sides to 50 $\Omega$		-80		dB
V <sub>STBUS_SBU</sub>	Short-to-VBUS tolerance on the SBU pins	Hot-Plug C_SBUx with a 1 meter USB Type C Cable. Put a 100-nF capacitor in series with a $40-\Omega$ resistor to GND on SBUx			24	V
V <sub>STBUS_SBU_C</sub> LAMP	Short-to-VBUS system-side clamping voltage on the SBU pins (SBUx)	Hot-Plug C_SBUx with a 1 meter USB Type C Cable. Hot-Plug voltage C_SBUx = 24 V. VPWR = $3.3$ V. Put a 150-nF capacitor in series with a $40-\Omega$ resistor to GND on SBUx		8		V
POWER SUPP	PLY and LEAKAGE CURRENTS					
V <sub>PWR_UVLO</sub>	V <sub>PWR</sub> under voltage lockout	Place 1 V on VPWR and raise voltage until SBU or CC FETs turnon	2.1	2.3	2.5	V
V <sub>PWR_UVLO_H</sub> ys	V <sub>PWR</sub> UVLO hysteresis	Place 3 V on VPWR and lower voltage until SBU or CC FETs turnoff; measure difference between rising and falling UVLO to calculate hysteresis	100 150		200	mV
I <sub>VPWR</sub>	V <sub>PWR</sub> supply current	VPWR = 3.3 V (typical), VPWR = 4.5 V (maximum). $-40^{\circ}$ C $\leq$ T <sub>J</sub> $\leq$ +85°C.		90	135	μA
I <sub>CC_LEAK</sub>	Leakage current for CC pins when device is powered	VPWR = 3.3 V, VC_CCx = 3.6 V, CCx pins are floating, measure leakage into C_CCx pins. Result must be same if CCx side is biased and C_CCx is left floating			5	μA

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## **Electrical Characteristics (continued)**

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I <sub>SBU_LEAK</sub>	Leakage current for SBU pins when device is powered	$\label{eq:VPWR} \begin{array}{l} PWR = 3.3 \ V, \ VC\_SBUx = 3.6 \ V, \\ SBUx \ pins \ are \ floating, \ measure \\ leakge \ into \ C\_SBUx \ pins. \ Result \ must \\ be \ same \ if \ SBUx \ side \ is \ biased \ and \\ C\_SBUx \ is \ left \ floating. \ -40^\circC \le T_J \le \\ +85^\circC \end{array}$			3	μΑ
I <sub>C_CC_LEAK_OV</sub> P	Leakage current for CC pins when device is in OVP	VPWR = 0 V or 3.3 V, VC_CCx = 24 V, CCx pins are set to 0 V, measure leakage into C_CCx pins			1200	μΑ
I <sub>C_SBU_LEAK_O</sub> VP	Leakage current for SBU pins when device is in OVP	VPWR = 0 V or 3.3 V, VC_SBUx = 24 V, SBUx pins are set to 0 V, measure leakage into C_SBUx pins			400	μA
I <sub>CC_LEAK_OVP</sub>	Leakage current for CC pins when device is in OVP	VPWR = 0 V or 3.3 V, VC_CCx = 24 V, CCx pins are set to 0 V, measure leakage out of CCx pins			30	μA
I <sub>SBU_LEAK_OVP</sub>	Leakage current for SBU pins when device is in OVP	VPWR = 0 V or 3.3 V, VC_SBUx = 24 V, SBUx pins are set to 0 V, measure leakage out of SBUx pins	-1		1	μA
I <sub>Dx_LEAK</sub>	Leakage current for Dx pins	V_Dx = 3.6 V, measure leakage into Dx pins			1	μA
FLT PIN						
V <sub>OL</sub>	Low-level output voltage	IOL = 3 mA. Measure the voltage at the FLT pin			0.4	V
OVER TEMPE	RATURE PROTECTION				·	
T <sub>SD_RISING</sub>	The rising over-temperature protection shutdown threshold		150	175		°C
T <sub>SD_FALLING</sub>	The falling over-temperature protection shutdown threshold		130	140		°C
T <sub>SD_HYST</sub>	The over-temperature protection shutdown threshold hysteresis			35		°C
Dx ESD PROT	ECTION					
V <sub>RWM_POS</sub>	Reverse stand-off voltage from Dx to GND	Dx to GND. I <sub>DX</sub> ≤ 1 μA			5.5	V
V <sub>RWM_NEG</sub>	Reverse stand-off voltage from GND to Dx	GND to Dx			0	V
V <sub>BR_POS</sub>	Break-down voltage from Dx to GND	Dx to GND. $I_{BR} = 1 \text{ mA}$	7			V
V <sub>BR_NEG</sub>	Break-down voltage from GND to Dx	GND to Dx. $I_{BR} = 8 \text{ mA}$	0.6			V
C <sub>IO</sub>	Dx to GND or GND to Dx	f = 1 MHz, VIO = 2.5 V		1.7		pF
ΔC <sub>IO</sub>	Differential capacitance between two Dx pins	f = 1 MHz, VIO = 2.5 V		0.02		pF
R <sub>DYN</sub>	Dynamic on-resistance Dx IEC clamps	Dx to GND or GND to Dx		0.4		Ω

## 7.7 Timing Requirements

		MIN	NOM	MAX	UNIT
POWER-ON and Off TIM	MINGS				
t <sub>ON</sub>	Time from crossing rising VPWR UVLO until CC and SBU OVP FETs are on			3.5	ms
dV <sub>PWR_OFF</sub> /dt	Minimum Slew rate allowed to guarantee CC and SBU FETs turnoff during a power off	-0.5			V/µs
OVER VOLTAGE PROT	ECTION				
tovp_response_cc	OVP response time on the CC pins. Time from OVP asserted until OVP FETs turnoff		70		ns

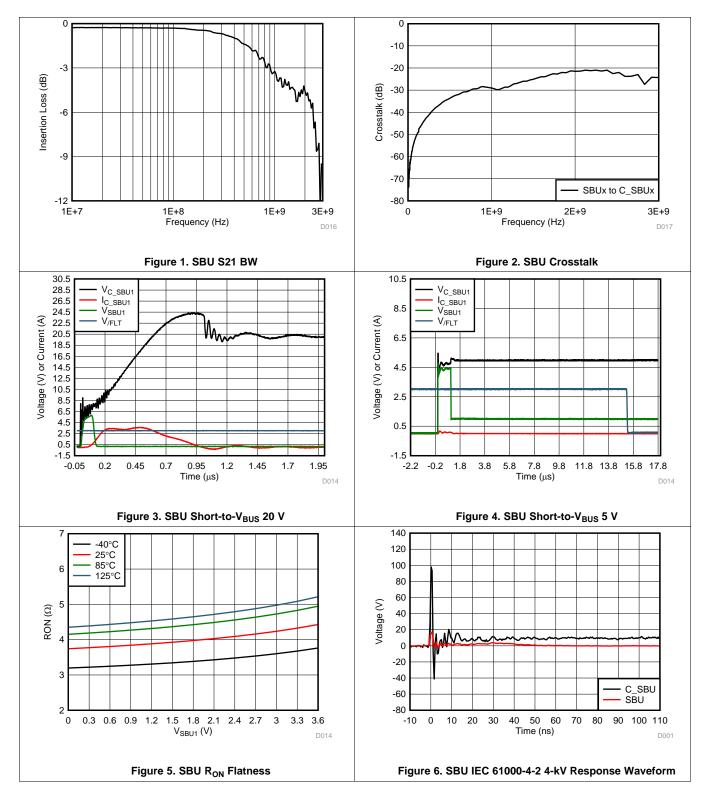
## Timing Requirements (continued)

		MIN	NOM	MAX	UNIT
t <sub>OVP_RESPONSE_SBU</sub>	OVP response time on the SBU pins. Time from OVP asserted until OVP FETs turnoff		80		ns
tovp_recovery_cc_1	OVP recovery time on the CC pins. Once an OVP has occurred, the minimum time duration until the CC FETs turn back on. OVP must be removed for CC FETs to turn back on	21	29	39	ms
tovp_recovery_sbu_1	OVP recovery time on the SBU pins. Once an OVP has occurred, the minimum time duration until the SBU FETs turn back on. OVP must be removed for SBU FETs to turn back on	21	29	39	ms
tovp_recovery_cc_2	OVP recovery time on the CC pins. Time from OVP Removal until CC FET turns back on, if device has been in OVP > 40 ms		0.5		ms
tovp_recovery_sbu_2	OVP recovery time on the SBU pins. Time from OVP Removal until SBU FET turns back on, if device has been in OVP > 40 ms		0.5		ms
t <sub>OVP_FLT_ASSERTION</sub>	Time from OVP asserted to FLT assertion		20		μs
tovp_flt_deassertion	Time from CC FET turnon after an OVP to $\overline{\text{FLT}}$ deassertion		5		ms

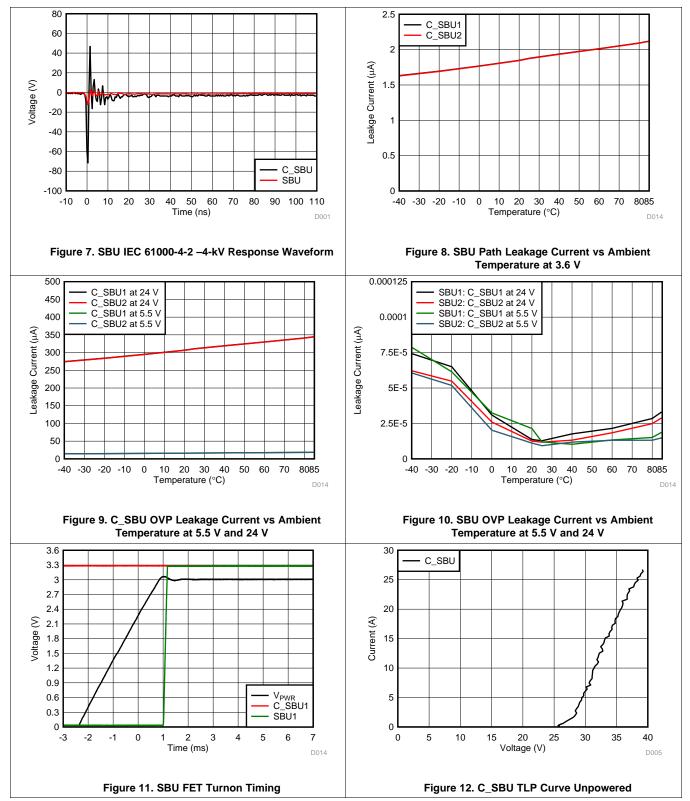
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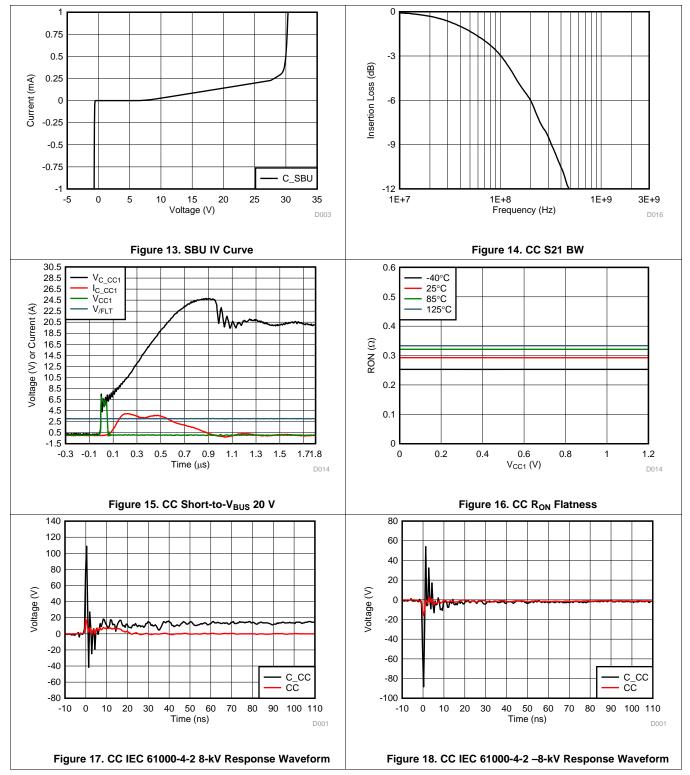
## 7.8 Typical Characteristics



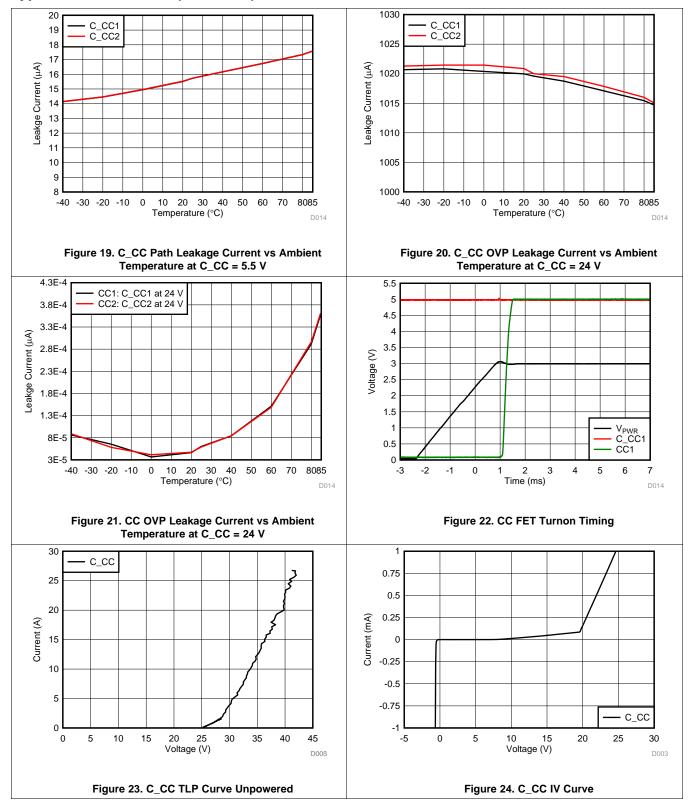








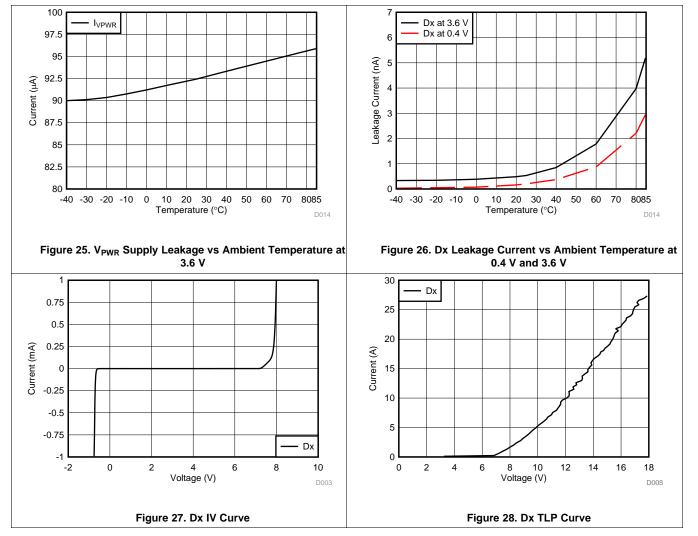




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## 8 Detailed Description

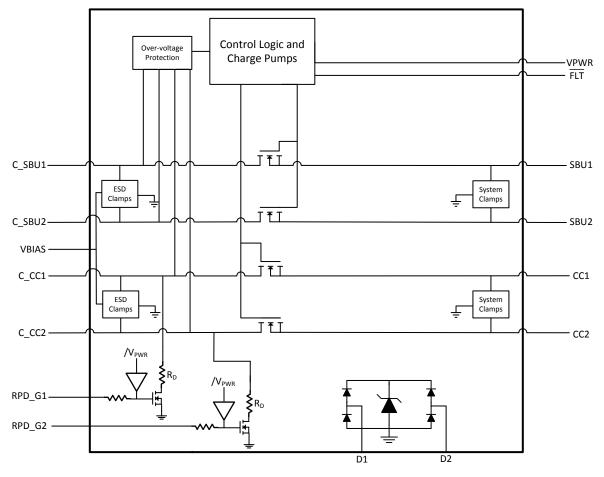
## 8.1 Overview

The TPD6S300 is a single chip USB Type-C port protection solution that provides 20-V Short-to-V<sub>BUS</sub> overvoltage and IEC ESD protection. Due to the small pin pitch of the USB Type-C connector and non-compliant USB Type-C cables and accessories, the V<sub>BUS</sub> pins can get shorted to the CC and SBU pins inside the USB Type-C connector. Because of this short-to-V<sub>BUS</sub> event, the CC and SBU pins need to be 20-V tolerant, to support protection on the full USB PD voltage range. Even if a device does not support 20-V operation on V<sub>BUS</sub>, non complaint adaptors can start out with 20-V V<sub>BUS</sub> condition, making it necessary for any USB Type-C device to support 20 V protection. The TPD6S300 integrates four channels of 20-V Short-to-V<sub>BUS</sub> overvoltage protection for the CC1, CC2, SBU1, and SBU2 pins of the USB Type-C connector.

Additionally, IEC 61000-4-2 system level ESD protection is required in order to protect a USB Type-C port from ESD strikes generated by end product users. The TPD6S300 integrates eight channels of IEC61000-4-2 ESD protection for the CC1, CC2, SBU1, SBU2, DP\_T (Top side D+), DM\_T (Top Side D–), DP\_B (Bottom Side D+), and DM\_B (Bottom Side D–) pins of the USB Type-C connector. This means IEC ESD protection is provided for all of the low-speed pins on the USB Type-C connector in a single chip in the TPD6S300. Additionally, high-voltage IEC ESD protection that is 22-V DC tolerant is required for the CC and SBU lines in order to simultaneously support IEC ESD and Short-to-V<sub>BUS</sub> protection; there are not many discrete market solutions that can provide this kind of protection. This high-voltage IEC ESD diode is what the TPD6S300 integrates, specifically designed to guarantee it works in conjunction with the overvoltage protection FETs inside the device. This sort of solution is very hard to generate with discrete components.



## 8.2 Functional Block Diagram



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## 8.3 Feature Description

## 8.3.1 4-Channels of Short-to-V<sub>BUS</sub> Overvoltage Protection (CC1, CC2, SBU1, SBU2 Pins): 24-V<sub>DC</sub> Tolerant

The TPD6S300 provides 4-channels of Short-to-V<sub>BUS</sub> Overvoltage Protection for the CC1, CC2, SBU1, and SBU2 pins of the USB Type-C connector. The TPD6S300 is able to handle  $24-V_{DC}$  on its C\_CC1, C\_CC2, C\_SBU1, and C\_SBU2 pins. This is necessary because according to the USB PD specification, with V<sub>BUS</sub> set for 20-V operation, the V<sub>BUS</sub> voltage is allowed to legally swing up to 21 V, and 21.5 V on voltage transitions from a different USB PD V<sub>BUS</sub> voltage. The TPD6S300 builds in tolerance up to  $24-V_{BUS}$  to provide margin above this 21.5 V specification to be able to support USB PD adaptors that may break the USB PD specification.

When a short-to- $V_{BUS}$  event occurs, ringing happens due to the RLC elements in the hot-plug event. With very low resistance in this RLC circuit, ringing up to twice the settling voltage can appear on the connector. More than 2x ringing can be generated if any capacitor on the line derates in capacitance value during the short-to- $V_{BUS}$  event. This means that more than 44 V could be seen on a USB Type-C pin during a Short-to- $V_{BUS}$  event. The TPD6S300 has built in circuit protection to handle this ringing. The diode clamps used for IEC ESD protection also clamp the ringing voltage during the short-to- $V_{BUS}$  event to limit the peak ringing to around 30 V. Additionally, the overvoltage protection FETs integrated inside the TPD6S300 are 30-V tolerant, therefore being capable of supporting the high-voltage ringing waveform that is experienced during the short-to- $V_{BUS}$  event. The well designed combination of voltage clamps and 30-V tolerant OVP FETs insures the TPD6S300 can handle Short-to- $V_{BUS}$  hot-plug events with hot-plug voltages as high as 24- $V_{DC}$ .

#### Feature Description (continued)

The TPD6S300 has an extremely fast turnoff time of 70 ns typical. Furthermore, additional voltage clamps are placed after the OVP FET on the system side (CC1, CC2, SBU1, SBU2) pins of the TPD6S300, to further limit the voltage and current that are exposed to the USB Type-C CC/PD controller during the 70 ns interval while the OVP FET is turning off. The combination of connector side voltage clamps, OVP FETs with extremely fast turnoff time, and system side voltage clamps all work together to insure the level of stress seen on a CC1, CC2, SBU1, or SBU2 pin during a short-to-V<sub>BUS</sub> event is less than or equal to an HBM event. This is done by design, as any USB Type-C CC/PD controller will have built in HBM ESD protection.

Figure 29 is an example of the TPD6S300 successfully protecting the TPS65982, the world's first fully integrated, full-featured USB Type-C and PD controller.

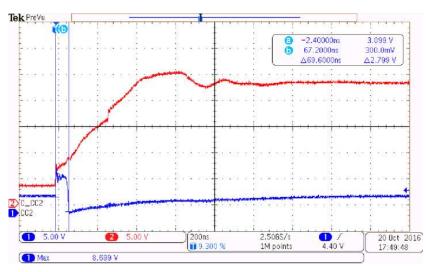


Figure 29. TPD6S300 Protecting the TPS65982 During a Short-to-V<sub>BUS</sub> Event

#### 8.3.2 8-Channels of IEC 61000-4-2 ESD Protection (CC1, CC2, SBU1, SBU2, DP\_T, DM\_T, DP\_B, DM\_B Pins)

The TPD6S300 integrates 8-Channels of IEC 61000-4-2 system level ESD protection for the CC1, CC2, SBU1, SBU2, DP\_T (Top side D+), DM\_T (Top Side D-), DP\_B (Bottom Side D+), and DM\_B (Bottom Side D-) pins. USB Type-C ports on end-products need system level IEC ESD protection in order to provide adequate protection for the ESD events that the connector can be exposed to from end users. The TPD6S300 integrates IEC ESD protection for all of the low-speed pins on the USB Type-C connector in a single chip. Also note, that while the RPD\_Gx pins are not individually rated for IEC ESD, when they are shorted to the C\_CCx pins, the C\_CCx pins provide protection for both the C\_CCx pins and the RPD\_Gx pins. Additionally, high-voltage IEC ESD protection that is 24-V DC tolerant is required for the CC and SBU lines in order to simultaneously support IEC ESD and Short-to-V<sub>BUS</sub> protection; there are not many discrete market solutions that can provide this kind of protection. The TPD6S300 integrates this type of high-voltage ESD protection so a system designer can meet both IEC ESD and Short-to-V<sub>BUS</sub> protection requirements in a single device.

#### 8.3.3 CC1, CC2 Overvoltage Protection FETs 600 mA Capable for Passing VCONN Power

The CC pins on the USB Type-C connector serve many functions; one of the functions is to be a provider of power to active cables. Active cables are required when desiring to pass greater than 3 A of current on the V<sub>BUS</sub> line or when the USB Type-C port uses the super-speed lines (TX1+, TX2–, RX1+, RX1–, TX2+, TX2–, RX2+, RX2–). When CC is configured to provide power, it is called VCONN. VCONN is a DC voltage source in the range of 3 V-5.5 V. If supporting VCONN, a VCONN provider must be able to provide 1 W of power to a cable; this translates into a current range of 200 mA to 333 mA (depending on your VCONN voltage level). Additionally, if operating in a USB PD alternate mode, greater power levels are allowed on the VCONN line.



#### Feature Description (continued)

When a USB Type-C port is configured for VCONN and using the TPD6S300, this VCONN current flows through the OVP FETs of the TPD6S300. Therefore, the TPD6S300 has been designed to handle these currents and have an RON low enough to provide a specification compliant VCONN voltage to the active cable. The TPD6S300 is designed to handle up to 600 mA of DC current to allow for alternate mode support in addition to the standard 1 W required by the USB Type-C specification.

#### 8.3.4 CC Dead Battery Resistors Integrated for Handling the Dead Battery Use Case in Mobile Devices

An important feature of USB Type-C and USB PD is the ability for this connector to serve as the sole power source to mobile devices. With support up to 100 W, the USB Type-C connector supporting USB PD can be used to power a whole new range of mobile devices not previously possible with legacy USB connectors.

When the USB Type-C connector is the sole power supply for a battery powered device, the device must be able to charge from the USB Type-C connector even when its battery is dead. In order for a USB Type-C power adapter to supply power on  $V_{BUS}$ , RD pull-down resistors must be exposed on the CC pins. These RD resistors are typically included inside a USB Type-C CC/PD controller. However, when the TPD6S300 is used to protect the USB Type-C port, the OVP FETs inside the device isolate these RD resistors in the CC/PD controller when the mobile device has no power. This is because when the TPD6S300 has no power, the OVP FETs are turned off to guarantee overvoltage protection in a dead battery condition. Therefore, the TPD6S300 integrates high-voltage, dead battery RD pull-down resistors to allow dead battery charging simultaneously with high-voltage OVP protection.

If dead battery support is required, short the RPD\_G1 pin to the C\_CC1 pin, and short the RPD\_G2 pin to the C\_CC2 pin. This connects the dead battery resistors to the connector CC pins. When the TPD6S300 is unpowered, and the RP pull-up resistor is connected from a power adaptor, this RP pull-up resistor activates the RD resistor inside the TPD6S300. This enables  $V_{BUS}$  to be applied from the power adaptor even in a dead battery condition. Once power is restored back to the system and back to the TPD6S300 on its VPWR pin, the TPD6S300 removes its RD pull-down resistor and turnon its OVP FETs within 3.5 ms to guarantee the RD pull-down resistor inside the CC/PD Controller is exposed within 10 ms. This is by design, because if the RD pull-down resistor is not exposed within 10 ms, the power adaptor can legally interpret this behavior as a port disconnect and remove  $V_{BUS}$ .

If desiring to power the CC/PD controller during dead battery mode and if the CC/PD Controller is configured as a DRP, it is critical that the TPD6S300 be powered before or at the same time that the CC/PD controller is powered. It is also critical that when unpowered, the CC/PD controller also expose its dead battery resistors. When the TPD6S300 gets powered, it exposes the CC pins of the CC/PD controller within 3.5 ms. Once the TPD6S300 turns on, the RD pull-down resistors of the CC/PD controller must be present immediately, in order to guarantee the power adaptor connected to power the dead battery device keeps its V<sub>BUS</sub> turned on. If the power adaptor sees any change to its CC voltage for more than 10 ms, it can disconnect V<sub>BUS</sub>. This removes power from the device with its battery still not sufficiently charged, which consequently removes power from the CC/PD controller and the TPD6S300. Then the RD resistors of the TPD6S300 are exposed again, connect the power adaptor's V<sub>BUS</sub> to start the cycle over. This creates an infinite loop, never or very slowly charging the mobile device.

If the CC/PD Controller is configured for DRP and has started its DRP toggle before the TPD6S300 turns on, this DRP toggle is unable to guarantee that the power adaptor does not disconnect from the port. Therefore, it is recommended if the CC/PD controller is configured for DRP, that its dead battery resistors be exposed as well, and that they remain exposed until the TPD6S300 turns on. This is typically accomplished by powering the TPD6S300 at the same time as the CC/PD controller when powering the CC/PD controller in dead battery operation.

If dead battery charging is not required in your application, connect the RPD\_G1 and RPD\_G2 pins to ground.

#### 8.3.5 3-mm × 3-mm WQFN Package

The TPD6S300 comes in a small, 3-mm × 3-mm WQFN package, greatly reducing the size of implementing a similar protection solution discretely. The WQFN package allows support for a wider range of PCB designs. Additionally, the pin-out of the TPD6S300 was designed to optimize routing with the TPS6598x family of USB Type-C/PD controllers.



#### 8.4 Device Functional Modes

Table 1 describes all of the functional modes for the TPD6S300. The "X" in the below table are "do not care" conditions, meaning any value can be present within the absolute maximum ratings of the datasheet and maintain that functional mode. Also note the D1, D2, D3, D4 pins are not listed, because these pins have IEC ESD protection diodes that are always present, regardless of whether the device is powered and regardless of the conditions on any of the other pins.

Device Mode Table		Inputs					Outputs			
MC	ODE	VPWR	C_CCx	C_SBUx	RPD_Gx	TJ	FLT	CC FETs	SBU FETs	
Normal	Unpowered, no dead battery support	<uvlo< th=""><th>х</th><th>Х</th><th>Grounded</th><th>Х</th><th>High-Z</th><th>OFF</th><th>OFF</th></uvlo<>	х	Х	Grounded	Х	High-Z	OFF	OFF	
Operating Conditions	Unpowered, dead battery support	<uvlo< td=""><td>х</td><td>Х</td><td>Shorted to C_CCx</td><td>Х</td><td>High-Z</td><td>OFF</td><td>OFF</td></uvlo<>	х	Х	Shorted to C_CCx	Х	High-Z	OFF	OFF	
	Powered on	>UVLO	<ovp< td=""><td><ovp< td=""><td>X, forced OFF</td><td><tsd< td=""><td>High-Z</td><td>ON</td><td>ON</td></tsd<></td></ovp<></td></ovp<>	<ovp< td=""><td>X, forced OFF</td><td><tsd< td=""><td>High-Z</td><td>ON</td><td>ON</td></tsd<></td></ovp<>	X, forced OFF	<tsd< td=""><td>High-Z</td><td>ON</td><td>ON</td></tsd<>	High-Z	ON	ON	
	Thermal shutdown	>UVLO	х	х	X, forced OFF	>TSD	Low (Fault Asserted)	OFF	OFF	
Fault Conditions	CC over voltage condition	>UVLO	>OVP	х	X, forced OFF	<tsd< td=""><td>Low (Fault Asserted)</td><td>OFF</td><td>OFF</td></tsd<>	Low (Fault Asserted)	OFF	OFF	
	SBU over voltage condition	>UVLO	х	>OVP	X, forced OFF	<tsd< td=""><td>Low (Fault Asserted)</td><td>OFF</td><td>OFF</td></tsd<>	Low (Fault Asserted)	OFF	OFF	

#### Table 1. Device Mode Table

INSTRUMENTS

EXAS

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## 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

The TPD6S300 provides 4-channels of Short-to-VBUS overvoltage protection for the CC1, CC2, SBU1, and SBU2 pins of the USB Type-C connector, and 8-channels of IEC ESD protection for the CC1, CC2, SBU1, SBU2, DP\_T, DM\_T, DP\_B, DM\_B pins of the USB Type-C connector. Care must be taken to insure that the TPD6S300 provides adequate system protection as well as insuring that proper system operation is maintained. The following application example explains how to properly design the TPD6S300 into a USB Type-C system.

## 9.2 Typical Application

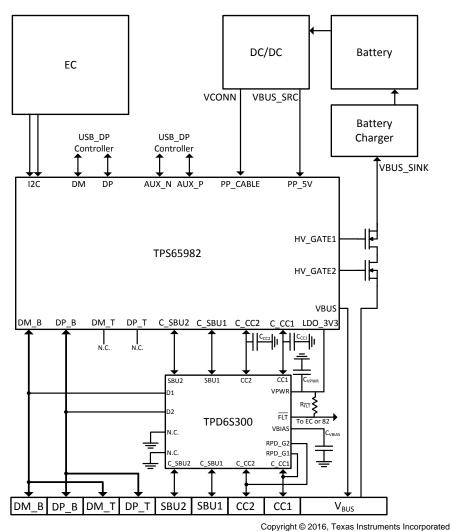


Figure 30. TPD6S300 Typical Application Diagram



## **Typical Application (continued)**

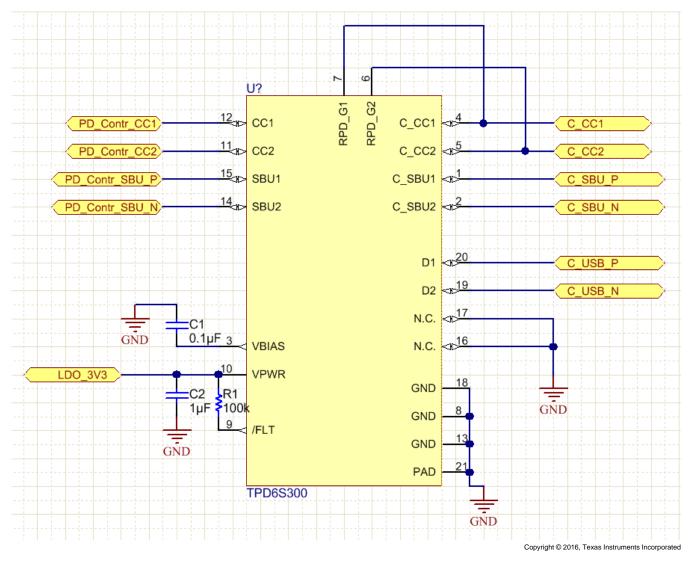


Figure 31. TPD6S300 Reference Schematic

## 9.2.1 Design Requirements

In this application example we study the protection requirements for a full-featured USB Type-C DRP Port, fully equipped with USB-PD, USB2.0, USB3.0, Display Port, and 100 W charging. The TPS65982 is used to easily enable a full-featured port with a single chip solution. In this application, all the pins of the USB Type-C connector are utilized. Both the CC and SBU pins are susceptible to shorting to the V<sub>BUS</sub> pin. With 100 W charging, V<sub>BUS</sub> operates at 20 V, requiring the CC and SBU pins to tolerate 20-V<sub>DC</sub>. Additionally, the CC, SBU, and USB2.0 pins require IEC system level ESD protection. With these protection requirements present for the USB Type-C connector, the TPD6S300 is utilized. The TPD6S300 is a single chip solution that provides all the required protection for the low speed and USB2.0 pins in the USB Type-C connector.

Table 2 lists the TPD6S300 design parameters.

Table 2. Design	Parameters
-----------------	------------

DESIGN PARAMETER	EXAMPLE VALUE		
V <sub>BUS</sub> nominal operating voltage	20 V		
Short-to-V <sub>BUS</sub> tolerance for the CC and SBU pins	24 V		

DESIGN PARAMETER	EXAMPLE VALUE
VBIAS nominal capacitance	0.1 μF
Dead battery charging	100 W
Maximum ambient temperature requirement	85°C

#### Table 2. Design Parameters (continued)

#### 9.2.2 Detailed Design Procedure

#### 9.2.2.1 VBIAS Capacitor Selection

As noted in the *Recommended Operating Conditions* table, a minimum of  $35-V_{BUS}$  rated capacitor is required for the VBIAS pin, and a  $50-V_{BUS}$  capacitor is recommended. The VBIAS capacitor is in parallel with the central IEC diode clamp integrated inside the TPD6S300. A forward biased hiding diode connects the VBIAS pin to the C\_CCx and C\_SBUx pins. Therefore, when a Short-to-V<sub>BUS</sub> event occurs at 20 V,  $20-V_{BUS}$  minus a forward biased diode drop is exposed to the VBIAS pin. Additionally, during the short-to-V<sub>BUS</sub> event, ringing can occur almost double the settling voltage of 20 V, allowing a potential 40 V to be exposed to the C\_CCx and C\_SBUx pins. However, the internal IEC clamps limit the voltage exposed to the C\_CCx and C\_SBUx pins to around 30 V. Therefore, at least  $35-V_{BUS}$  capacitor is required to insure the VBIAS capacitor does not get destroyed during Short-to-V<sub>BUS</sub> events.

A 50-V, X7R capacitor is recommended, however. This is to further improve the derating performance of the capacitors. When the voltage across a real capacitor is increased, its capacitance value derates. The more the capacitor derates, the greater than 2x ringing can occur in the short-to- $V_{BUS}$  RLC circuit. 50-V X7R capacitors have great derating performance, allowing for the best short-to- $V_{BUS}$  performance of the TPD6S300.

Additionally, the VBIAS capacitor helps pass IEC 61000-4-2 ESD strikes. The more capacitance present, the better the IEC performance. So the less the VBIAS capacitor derates, the better the IEC performance. Table 3 shows real capacitors recommended to achieve the best performance with the TPD6S300.

CAPACITOR SIZE	PART NUMBER
0402	CC0402KRX7R9BB104
0603	GRM188R71H104KA93D

#### **Table 3. Design Parameters**

#### 9.2.2.2 Dead Battery Operation

For this application, we want to support 100-W dead battery operation; when the laptop is out of battery, we still want to charge the laptop at 20 V and 5 A. This means that the USB PD Controller must receive power in dead battery mode. The TPS65982 has its own built in LDO in order to supply the TPS65982 power from  $V_{BUS}$  in a dead battery condition. The TPS65982 can also provide power to its flash during this condition through its LDO\_3V3 pin.

The TPD6S300s OVP FETs remain OFF when it is unpowered in order to insure in a dead battery situation proper protection is still provided to the PD controller in the system, in this case the TPS65982. However, when the OVP FETs are OFF, this isolates the TPS65982s dead battery resistors from the USB Type-C ports CC pins. A USB Type-C power adaptor must see the RD pull-down dead battery resistors on the CC pins or it does not provide power on  $V_{BUS}$ . Since the TPS65982s dead battery resistors are isolated from the USB Type-C connector's CC pins, the TPD6S300s built in dead battery resistors must be connected. Short the RPD\_G1 pin to the C\_CC1 pin, and short the RPD\_G2 pin to the C\_CC2 pin.

Once the power adaptor sees the TPD6S300s dead battery resistors, it applies 5 V on the  $V_{BUS}$  pin. This provides power to the TPS65982, turning the PD controller on, and allowing the battery to begin to charge. However, this application requires 100 W charging in dead battery mode, so  $V_{BUS}$  at 20 V and 5 A is required. USB PD negotiation is required to accomplish this, so the TPS65982 needs to be able to communicate on the CC pins. This means the TPD6S300 needs to be turned on in dead battery mode as well so the TPD65982s PD controller can be exposed to the CC lines. To accomplish this, it is critical that the TPD6S300 is powered by the TPS65982s internal LDO, the LDO\_3V3 pin. This way, when the TPS65982 receives power on  $V_{BUS}$ , the TPD6S300 is turned on simultaneously.



It is critical that the TPS65982s dead battery resistors are also connected to its CC pins for dead battery operation. Short the TPS65982s RPD\_G1 pin to its C\_CC1 pin, and its RPD\_G2 pin to its C\_CC2 pin. It is critical that the TPS65982s dead battery resistors are present; once the TPD6S300 receives power, removes its dead battery resistors and turns on its OVP FETs, RD pull-down resistors must be present on the CC line in order to guarantee the power adaptor stays connected. If RD is not present and the voltage on CC changes for more than 10 ms, the power adaptor interprets this as a disconnect and remove V<sub>BUS</sub>.

Also, it is important that the TPS65982s dead battery resistors are present so it properly boots up in dead battery operation with the correct voltages on its CC pins.

Once this process has occurred, the TPS65982 can start negotiating with the power adaptor through USB PD for higher power levels, allowing 100-W operation in dead battery mode.

For more information on the TPD6S300 dead battery operation, see the CC Dead Battery Resistors Integrated for Handling the Dead Battery Use Case in Mobile Devices section of the datasheet. Also, see Figure 32 for a waveform of the CC line when the TPD6S300 is turning on and exposing the TPS65982s dead battery resistors to the USB Type-C connector.

#### 9.2.2.3 CC Line Capacitance

USB PD has a specification for the total amount of capacitance that is required for proper USB PD BMC operation on the CC lines. The specification from section 5.8.6 of the USB PD Specification is given below in Table 4.

NAME	DESCRIPTION	MIN	MAX	UNIT	COMMENT
cReceiver	CC receiver capacitance	200	600	pF	The DFP or UFP system shall have capacitance within this range when not transmitting on the line

#### Table 4. USB PD cReceiver Specification

Therefore, the capacitance on the CC lines must stay in between 200 pF and 600 pF when USB PD is being used. Therefore, the combination of capacitances added to the system by the TPS65982, the TPD6S300, and any external capacitor must fall within these limits. Table 5 shows the analysis involved in choosing the correct external CC capacitor for this system, and shows that an external CC capacitor is required.

	-			
CC Capacitance	MIN	MAX	UNIT	COMMENT
CC line target capacitance	200	600	pF	From the USB PD Specification section
TPS65982 capacitance	70	120	pF	From the TPS65982 Datasheet
TPD6S300 capacitance	60	120	pF	From the table.
Proposed capacitor GRM033R71E221KA01D	110	330	pF	CAP, CERM, 220 pF, 25 V, ±10%, X7R, 0201 (For min and max, assume ±50% capacitance change with temperature and voltage derating to be overly conservative)
TPS65982 + TPD6S300 + GRM033R71E221KA01D	240	570	pF	Meets USB PD cReceiver specification

#### **Table 5. CC Line Capacitor Calculation**

#### 9.2.2.4 Additional ESD Protection on CC and SBU Lines

If additional IEC ESD protection is desired to be placed on either the CC or SBU lines, it is important that highvoltage ESD protection diodes be used. The maximum DC voltage that can be seen in USB PD is  $21-V_{BUS}$ , with 21.5 V allowed during voltage transitions. Therefore, an ESD protection diode must have a reverse stand off voltage higher than 21.5 V in order to guarantee the diode does not breakdown during a short-to-V<sub>BUS</sub> event and have large amounts of current flowing through it indefinitely, destroying the diode. A reverse stand off voltage of 24 V is recommended to give margin above 21.5 V in case USB Type-C power adaptors are released in the market which break the USB Type-C specification.

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Furthermore, due to the fact that the Short-to- $V_{BUS}$  event applies a DC voltage to the CC and SBU pins, a deepsnap back diode cannot be used unless its minimum trigger voltage is above 42 V. During a Short-to- $V_{BUS}$  event, RLC ringing of up to 2x the settling voltage can be exposed to CC and SBU, allowing for up to 42 V to be exposed. Furthermore, if any capacitor derates on the CC or SBU line, greater than 2x ringing can occur. Since this ringing is hard to bound, it is recommended to not use deep-snap back diodes. If the diode triggers during the short-to- $V_{BUS}$  hot-plug event, it begins to operate in is conduction region. With a 20- $V_{BUS}$  source present on the CC or SBU line, this allows the diode to conduct indefinitely, destroying the diode.

## 9.2.2.5 FLT Pin Operation

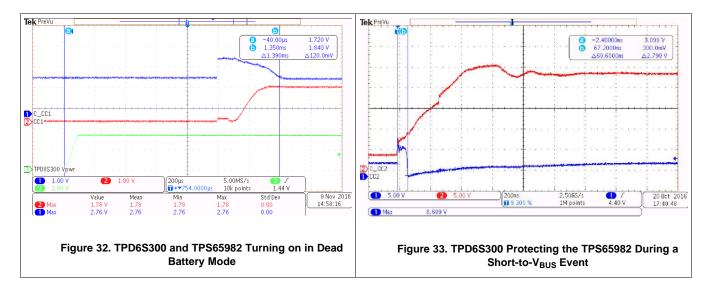
The  $\overline{FLT}$  and OVP FET have specific timing parameters to allow different benefits depending on how the system designer desires the system to respond to a Short-to-V<sub>BUS</sub> event.

Once a Short-to- $V_{BUS}$  occurs on the C\_CCx or C\_SBUx pins, the FLT pin is asserted in 20 µs (typical) so the PD controller can be notified quickly. If  $V_{BUS}$  is being shorted to CC or SBU, it is recommended to respond to the event by forcing a detach in the USB PD controller to remove  $V_{BUS}$  from the port. Although the USB Type-C port using the TPD6S300 is not damaged, as the TPD6S300 provides protection from these events, the other device connected through the USB Type-C Cable or any active circuitry in the cable can be damaged. Although shutting the  $V_{BUS}$  off through a detach does not guarantee it stops the other device or cable from being damaged, it can mitigate any high current paths from causing further damage after the initial damage takes place. Additionally, even if the active cable or other device does have proper protection, the short-to- $V_{BUS}$  event may corrupt a configuration in an active cable or in the other PD controller, so it is best to detach and reconfigure the port.

For UFP's, the TPD6S300 automatically forces a detach, removing the need to use the  $\overline{FLT}$  pin if the only response required by your system during a short-to-V<sub>BUS</sub> event is forcing a detach on the port. The TPD6S300 keeps its CC OVP FET OFF for at least 21 ms after a Short-to-V<sub>BUS</sub> event occurs, causing the CC line voltage to change from is configuration value for more than 20 ms, forcing the PD controllers to detach. For DFPs, this operation cannot be guaranteed because of the parasitic diode in the OVP FET from CCx to C\_CCx and from SBUx to C\_SBUx. Therefore for DFPs, using the FLT pin recommended. For our application using the TPS65982 as a DRP, using the FLT pin is recommended.

## 9.2.2.6 How to Connect Unused Pins

If either the RPD\_Gx pins or any of the Dx pins are unused in a design, they must be connected to GND.



## 9.2.3 Application Curves



## **10** Power Supply Recommendations

The VPWR pin provides power to all the circuitry in the TPD6S300. It is recommended a 1-µF decoupling capacitor is placed as close as possible to the VPWR pin. If USB PD is desired to be operated in dead battery conditions, it is critical that the TPD6S300 share the same power supply as the PD controller in dead battery boot-up (such as sharing the same dead battery LDO). See the *CC Dead Battery Resistors Integrated for Handling the Dead Battery Use Case in Mobile Devices* section for more details.



## 11 Layout

## 11.1 Layout Guidelines

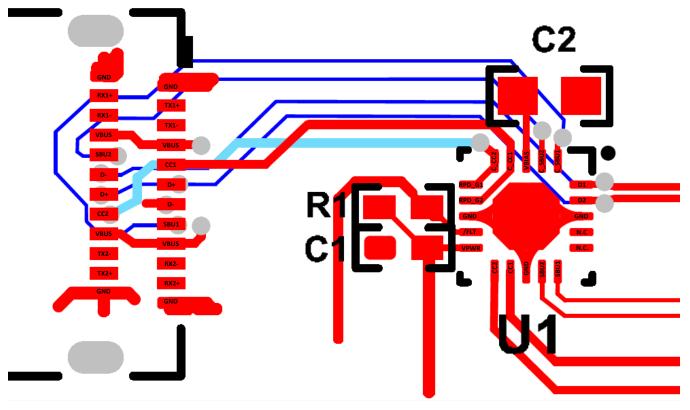
Proper routing and placement is important to maintain the signal integrity the USB2.0, SBU, CC line signals. The following guidelines apply to the TPD6S300:

- Place the bypass capacitors as close as possible to the V<sub>PWR</sub> pin, and ESD protection capacitor as close as
  possible to the V<sub>BIAS</sub> pin. Capacitors must be attached to a solid ground. This minimizes voltage disturbances
  during transient events such as short-to-V<sub>BUS</sub> and ESD strikes.
- The USB2.0 and SBU lines must be routed as straight as possible and any sharp bends must be minimized.

Standard ESD recommendations apply to the C\_CC1, C\_CC2, C\_SBU1, C\_SBU2, D1, D2, D3, and D4 pins as well:

- The optimum placement for the device is as close to the connector as possible:
  - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures.
  - The PCB designer must minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces which are between the TPD6S300 and the connector.
- Route the protected traces as straight as possible.
- Eliminate any sharp corners on the protected traces between the TVS and the connector by using rounded corners with the largest radii possible.
  - Electric fields tend to build up on corners, increasing EMI coupling.
- It is best practice to not via up to the D1, D2, D3, and D4 pins from a trace routed on another layer. Rather, it is better to via the trace to the layer with the Dx pin, and to continue that trace on that same layer. See the *ESD Protection Layout Guide* application report, section 1.3 for more details.

## 11.2 Layout Example







## **12 Device and Documentation Support**

## **12.1** Documentation Support

#### 12.1.1 Related Documentation

For related documentation see the following:

TPD6S300 Evaluation Module User's Guide

#### **12.2 Receiving Notification of Documentation Updates**

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### **12.3 Community Resources**

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.4 Trademarks

E2E is a trademark of Texas Instruments. USB Type-C is a trademark of USB Implementers Forum. All other trademarks are the property of their respective owners.

## 12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



10-Dec-2020

## PACKAGING INFORMATION

Orde	erable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPD	06S300RUKR	ACTIVE	WQFN	RUK	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	6S30	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(<sup>6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

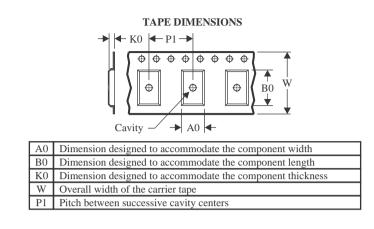
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## TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	-	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD6S300RUKR	WQFN	RUK	20	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPD6S300RUKR	WQFN	RUK	20	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2



# PACKAGE MATERIALS INFORMATION

14-Sep-2023



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPD6S300RUKR	WQFN	RUK	20	3000	367.0	367.0	35.0
TPD6S300RUKR	WQFN	RUK	20	3000	346.0	346.0	33.0

# **RUK 20**

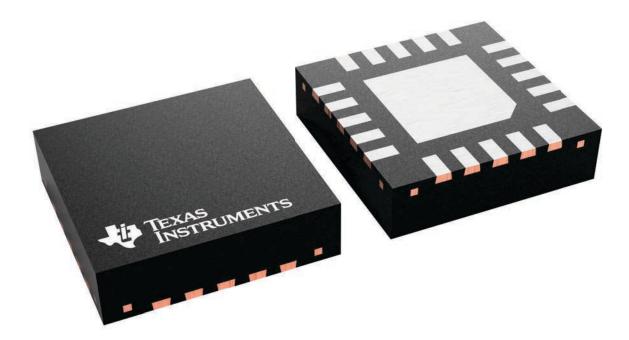
3 x 3, 0.4 mm pitch

# **GENERIC PACKAGE VIEW**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





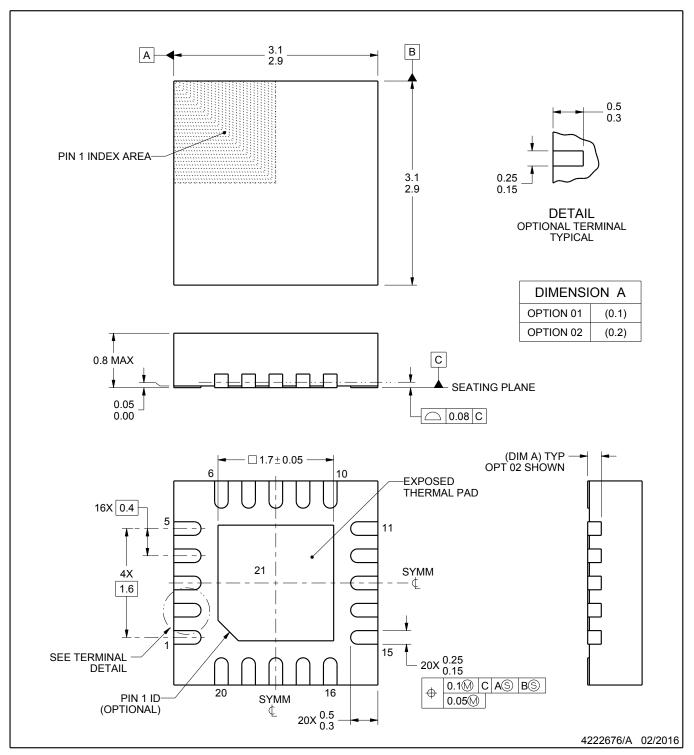
# **RUK0020B**



# **PACKAGE OUTLINE**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

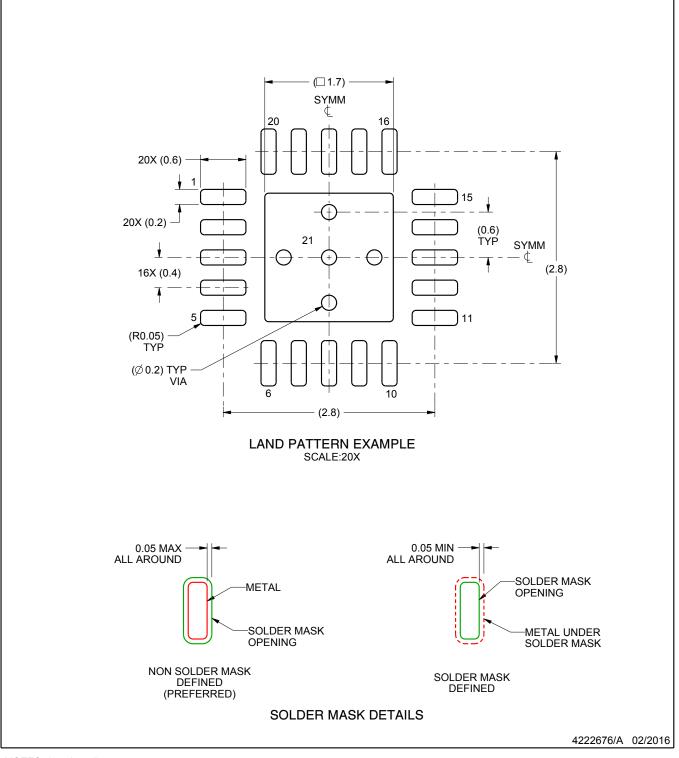


# **RUK0020B**

# **EXAMPLE BOARD LAYOUT**

## WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

 Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

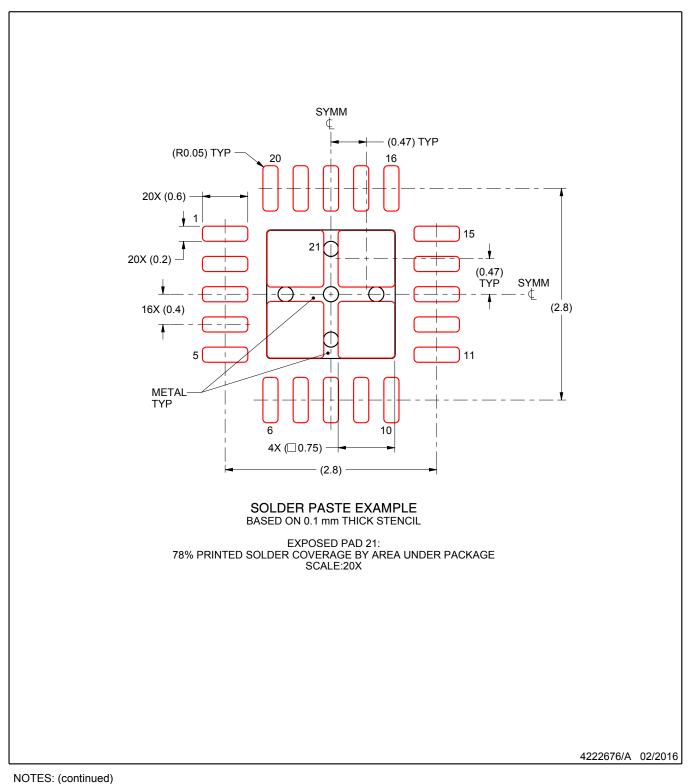


# **RUK0020B**

# **EXAMPLE STENCIL DESIGN**

# WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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